EAST Search History

Ref #	Hits	Search Query	DBs	Default Operato r	Plural s	Time Stamp
L1		10/540410	US-PGPU B; USPAT; USOCR; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/27 15:37
L2	8	("20020153527" "5576556" "5 786241" "6410373").PN.	US-PGPU B; USPAT; USOCR; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/27 15:38
L3	86	("20020153527" "5576556" "5 786241" "6410373")	US-PGPU B; USPAT; USOCR; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/27 15:56
L4	9	("20010015441" "20010025992" "20010048107" "20020001886" "5403761" "6228692" "6259138" "6303963" "6331723").PN.	US-PGPU B; USPAT; USOCR	OR	OFF	2006/10/27 15:49
L5	9	("20010015441" "20010025992" "20010048107" "20020001886" "5403761" "6228692" "6259138" "6303963" "6331723").PN.	US-PGPU B; USPAT; USOCR	OR	OFF	2006/10/27 17:01
L6	173193	transistor with gate	US-PGPU B; USPAT; USOCR	OR .	OFF	2006/10/27 17:01
L7	116939	transistor with gate same (source drain)	US-PGPU B; USPAT; USOCR	OR	OFF	2006/10/27 17:01

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L8	356	transistor with gate same (source drain) with (sidewall side adj wall wall near3 spacer) near5 (metal metallic conductive)	US-PGPU B; USPAT; USOCR	OR	ON	2006/10/27 17:19
L9	58	S8 and "LDD" same (source drain) with (sidewall side adj wall wall near3 spacer)	US-PGPU B; USPAT; USOCR	OR	ON	2006/10/27 17:19
L10	18	S9 and (source drain) with (silicide)	US-PGPU B; USPAT; USOCR	OR	ON	2006/10/27 17:14
L12	8028	gate same (metal metallic conductive polysilicon) near3 (sidewall side near3 wall wall near3 spacer spacer)	US-PGPU B; USPAT; USOCR	OR	ON	2006/10/27 17:22
L13	289	S12 and transistor with gate same (source drain) with (sidewall side adj wall wall near3 spacer) near5 (metal metallic conductive)	US-PGPU B; USPAT; USOCR	OR	ON	2006/10/27 17:23
L14	50	S13 and "LDD" same (source drain) with (sidewall side adj wall wall near3 spacer)	US-PGPU B; USPAT; USOCR	OR	ON	2006/10/27 17:23
L15	8028	gate same (metal metallic conductive polysilicon) near3 (sidewall side near3 wall wall near3 spacer spacer)	US-PGPU B; USPAT; USOCR	OR	ON	2006/10/27 17:21
L16	5995	gate same (metal metallic conductive polysilicon) near2 (sidewall side near3 wall wall near3 spacer spacer)	US-PGPU B; USPAT; USOCR	OR	ON	2006/10/27 17:22
L17	3619	gate same (metal metallic conductive polysilicon) near (sidewall side near3 wall wall near3 spacer spacer)	US-PGPU B; USPAT; USOCR	OR	ON	2006/10/27 17:22
L18	119	S17 and transistor with gate same (source drain) with (sidewall side adj wall wall near3 spacer) near5 (metal metallic conductive)	US-PGPU B; USPAT; USOCR	OR	ON	2006/10/27 17:23
L19	30	S18 and "LDD" same (source drain) with (sidewall side adj wall wall near3 spacer)	US-PGPU B; USPAT; USOCR	OR	ON	2006/10/27 17:23

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L20	5	("5039621" "5254490" "5439846" "5739066" "6103590").PN.	US-PGPU B; USPAT; USOCR	OR	OFF	2006/10/27 17:39
L21	6	("4521448" "4727038" "4804636" "4868617" "4925807" "4971922").PN.	US-PGPU B; USPAT; USOCR	OR	OFF	2006/10/27 17:46
L22	13	("4488351" "4587718" "4613882" "4616401" "4658496" "4680603" "4703551" "4727038" "4735680" "4753898" "4788160" "4824796" "4835112").PN.	US-PGPU B; USPAT; USOCR	OR	OFF	2006/10/27 17:50
L23	4	("4363696" "4597824" "4654680" "4746219").PN.	US-PGPU B; USPAT; USOCR	OR	OFF	2006/10/27 18:03
L24	12	("4510670" "4526665" "4528744" "4541166" "4558507" "4563805" "4575920" "4585517" "4587710" "4593454" "4613882" "4622735").PN.	US-PGPU B; USPAT; USOCR	OR	OFF	2006/10/27 18:15
L25	35	"4925807"	US-PGPU B; USPAT; USOCR	OR	OFF	2006/10/27 18:15